

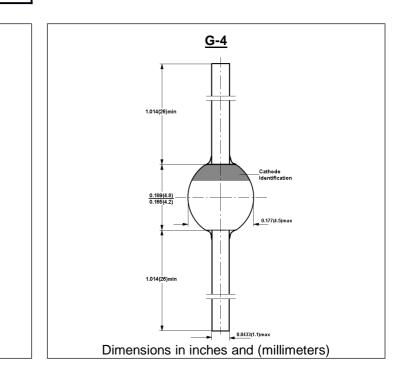
#### SINTERED GLASS JUNCTION FAST AVALANCHE RECTIFIER

VOLTAGE: 600V

# FEATURE

Glass passivated Hermetically sealed package Low reverse current Soft recovery characteristics





## **MECHANICAL DATA**

Case: G-4 sintered glass case Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C Polarity: color band denotes cathode end Mounting position: any

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

CURRENT: 3.0A

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	FE4J	units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	600	V
Maximum RMS Voltage	V <sub>RMS</sub>	420	V
Maximum DC blocking Voltage		600	V
Maximum Average Forward Rectified Current length at Ta=55 $^\circ\!\mathrm{C}$	3/8"lead I <sub>FAV</sub>	3.0	A
Peak Forward Surge Current 8.3ms single h wave superimposed on rated load	alf sine- I <sub>FSM</sub>	<u>100</u>	A
Maximum Forward Voltage at rated Forward and $25^\circ\!\!\!\!^\circ$	Current V <sub>F</sub>	1.6	V
Maximum DC Reverse Current at $V_{DC}$ =600V ar	id 25℃ I <sub>R</sub>	5.0	μΑ
Maximum DC Reverse Current at $V_{DC}$ =650V ar	ld 25℃ I <sub>R</sub>	5.0	μΑ
Maximum DC Reverse Current at $V_{DC}$ =700V ar	id 25℃ I <sub>R</sub>	25.0	μΑ
Maximum DC Reverse Current at $V_{DC}$ =600V ar	id 100℃ I <sub>R</sub>	100	μΑ
Maximum Reverse Recovery Time (1	Note 1) Trr	35	nS
Typical Junction Capacitance (	Note 2) Cj	100.0	pF
Typical Thermal Resistance (I	Note 3) Rth(ja)	20.0	°C /M
Storage and Operating Junction Temperature	Tstg, Tj	-65 to +175	°C

Note:

1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

#### **RATINGS AND CHARACTERISTIC CURVES FE4J**

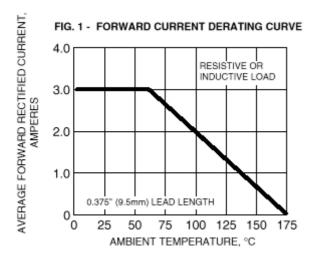
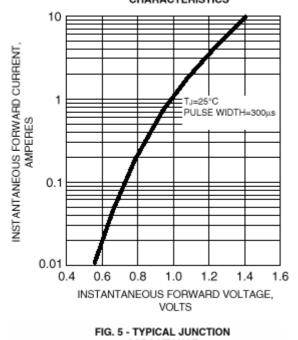
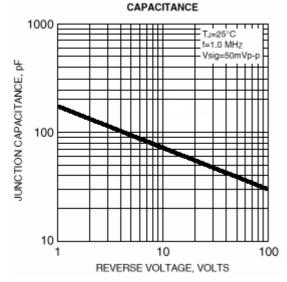


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS





Rev.A2

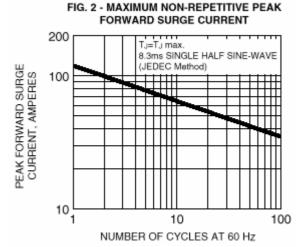


FIG. 4 - TYPICAL REVERSE CHARACTERISTIC

